



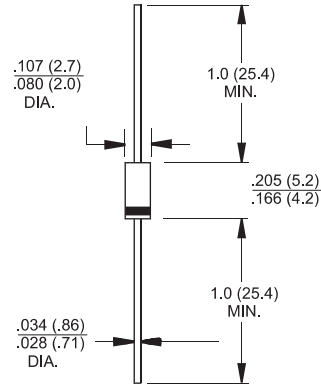
Features

- ✧ Glass passivated chip junction.
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed:
260 °C /10 seconds/.375", (9.5mm) lead lengths
at 5 lbs.,(2.3kg) tension
- ✧ Weight: 0.35 gram

DO-41



Dimensions in inches and (millimeters)

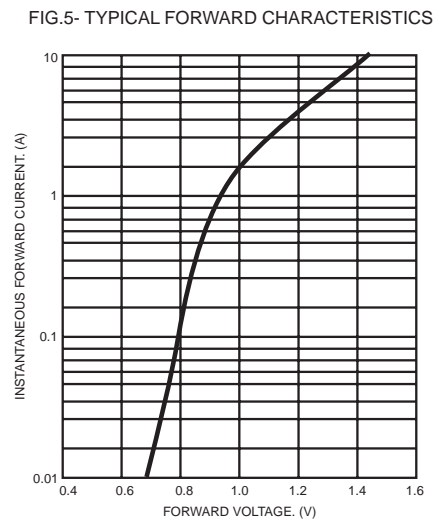
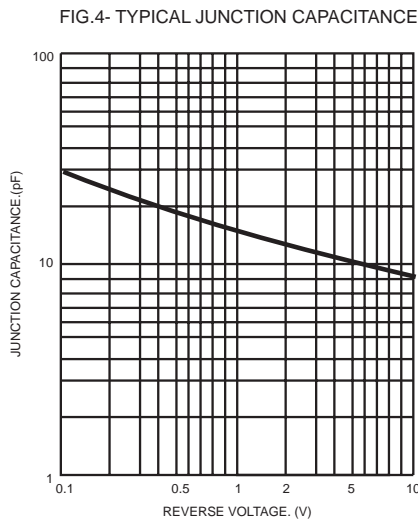
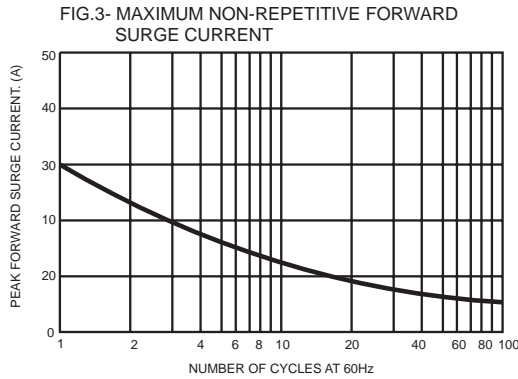
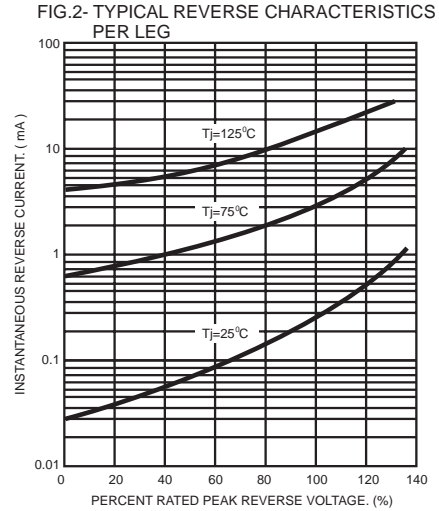
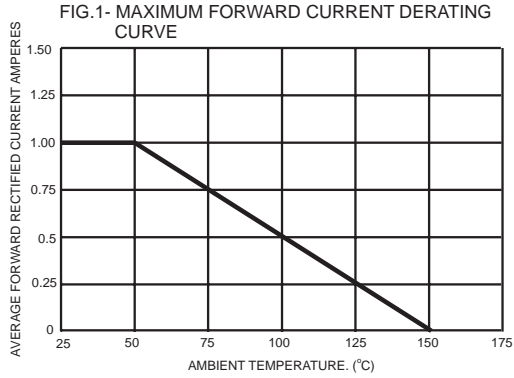
Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	1N	1N	1N	1N	1N	1N	1N	Units
		4001G	4002G	4003G	4004G	4005G	4006G	4007G	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length @ $T_A = 75^\circ C$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30							A
Maximum Instantaneous Forward Voltage @1.0A	V_F	1.0							V
Maximum DC Reverse Current @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$	I_R	5.0 50							μA μA
Typical Junction Capacitance (Note 1)	C_j	10							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	80							$^\circ C/W$
Operating and Storage Temperature Range	T_J, T_{STG}	- 65 to + 150							$^\circ C$

- Notes: 1. Measured at 1 MHz and Applied Reverse Voltage of 4.0 Volts D.C.
2. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

RATINGS AND CHARACTERISTIC CURVES (1N4001G THRU 1N4007G)



PACKAGE	SPQ/PCS	CARTON SPQ/PCS	CARTON SIZE/CM	CARTON GW/KG	CARTON NW/KG
DO-41	5000/AMMO	50000	42X28X31	14.00	12.00